Thyristor Semiconductor Device - Page 1 of 1



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| Inclosure Ma | terial: |
|------------------|--|
| Plastic | |
| Overall Leng | th: |
| 0.245 inches | |
| Terminal Len | igth: |
| 0.500 inches | |
| Overall Diam | eter: |
| 0.200 inches | |
| Internal Conf | iguration: |
| Unijunction | |
| Joint Electro | nic Device Engineering Council/jedec/case Outline Designation: |
| To-98 | |
| Electrode Inte | ernally-electrically Connected To Case: |
| Anode | |
| Mounting Me | thod: |
| Terminal | |
| Features Pro | vided: |
| Hermetically s | sealed case |
| Semiconduct | tor Material: |
| Silicon | |
| Power Rating | g Per Characteristic: |
| 300.0 milliwat | ts small-signal input power, common-collector preset |
| Maximum Op | perating Tempurature Per Measurement Point: |
| 100.0 degrees | s celsius ambient air |
| Special Featu | Jres: |
| Junction patte | ern arrangement: pnpn |
| Terminal Typ | e And Quantity: |
| 3 uninsulated | wire lead |
| Reference Nu | umber Differentiating Characteristics: |
| Material will be | e in accordance with ships parts control center activity hx quality control, manufacturing and testing specification |
| Shelf Life: | |
| N/a | |
| Unit Of Meas | ure: |
| | |
| Demilitarizati | ion: |
| No | |
| Fiig: | |
| A110a0 | |